



A Product Line of Diodes Incorporated

ZXTP25100CFH

100V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features

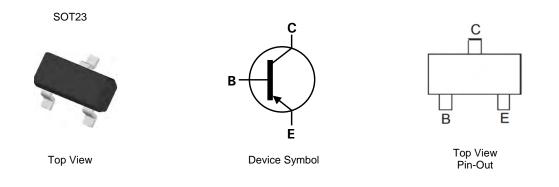
- BV_{CEO} > -100V
- Maximum Continuous Collector Current I_C = -1A
- V_{CE(sat)} < -220mV @ -1A
- R_{CE(sat)} = 150mΩ
- 7V reverse blocking voltage
- High peak current
- Complementary part number ZXTN25100CFH
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- UL Flammability Rating 94V-0
- Case material: molded Plastic.
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.008 grams (Approximate)

Applications

- MOSFET and IGBT gat driving
- DC DC converters
- Motor drive
- High side driver



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP25100CFHTA	1G5	7	8	3,000

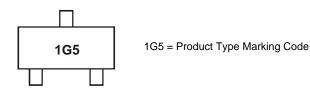
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-115	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-collector voltage (reverse blocking)	V _{ECO}	-7	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 5)	IC	-1	A
Base Current	Ι _Β	-500	mA
Peak Pulse Current	I _{CM}	-3	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		0.73		
Collector Dower Dissinction	(Note 6)	PD	1.05	W	
Collector Power Dissipation	(Note 7)		1.25		
	(Note 8)		1.81	ł	
	(Note 5)		171	°C/W	
Thermal Desistance Junction to Ambient	(Note 6)		119		
Thermal Resistance, Junction to Ambient	(Note 7)		100		
	(Note 8)		69		
Thermal Resistance, Junction to Leads	(Note 9)	R _{θJL}	75.25	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

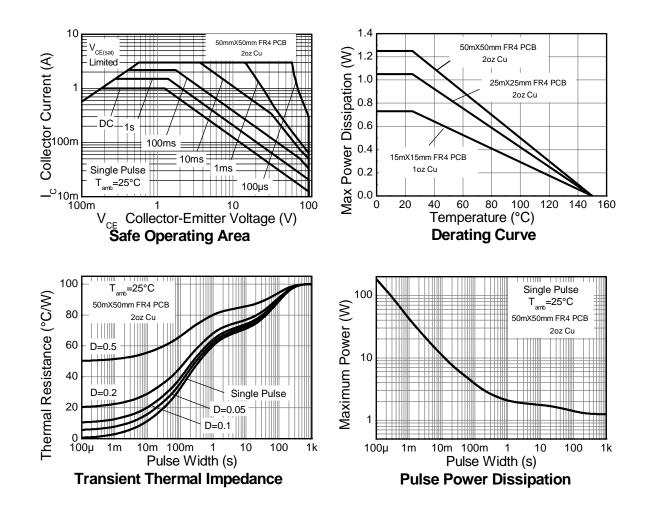
 For the device mounted on 15mm X 15mm X 1.6mm FR4 PCB with high coverage of single sided 1oz copper in still air condition;
Mounted on 25mm X 25mm X 1.6mm FR4 PCB with high coverage of single sided 2oz copper in still air condition
Mounted on 25mm X 25mm X 1.6mm FR4 PCB with high coverage of single sided 2oz copper in still air condition Notes:

8. As Note 7 above, measured at t < 5 secs.

9. Thermal resistance from junction to solder-point (at the end of the collector lead).



Thermal Characteristics @T_A = 25°C unless otherwise specified



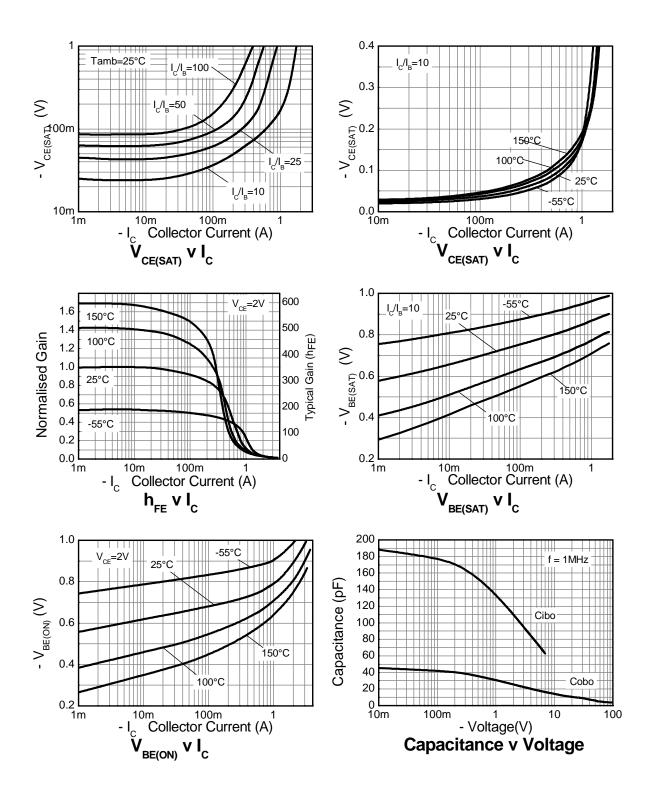


Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	-115	-180	-	V	I _C = -100μA	
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-140	-	V	$I_{\rm C} = -10 {\rm mA}$	
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.4	-	V	I _E = -100μA	
Emitter-Base Breakdown Voltage	BV _{ECX}	-7	-8.3	-	V	$I_E = -100\mu$ A, R _{BC} < 1kΩ or -0.25 < V _{BC} < 0.25V	
Emitter-Base Breakdown Voltage	BV _{ECO}	-7	-8.8	-	V	I _E = -100μA	
Collector-Base Cutoff Current		-	< -1	-50	nA	V _{CB} = -115V	
	I _{CBO}	-	-	-0.5	μA	$V_{CB} = -115V, T_{amb} = 100^{\circ}C$	
Collector-Emitter Cutoff Current	I _{CEX}	-	-	-100	nA	V_{CE} = -90V, R_{BE} < 1k Ω or -0.25V < V_{BE} < 1V	
Emitter-Base Cutoff Current	I _{EBO}	-	< -1	-50	nA	V _{EB} = -5.6V	
	hFE	200	350	500	-	$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$	
Statia Famuard Current Transfer Datia (Nata 10)		180	320	-		$I_{C} = -100 \text{mA}, V_{CE} = -2 \text{V}$	
Static Forward Current Transfer Ratio (Note 10)		110	190	-		$I_{C} = -500 \text{mA}, V_{CE} = -2 \text{V}$	
		20	35	-		$I_{C} = -1A, V_{CE} = -2V$	
	V _{CE(sat)}	-	-140	-210	mV	$I_{C} = -100 \text{mA}, I_{B} = -1 \text{mA}$	
Collector-Emitter Saturation Voltage (Note 10)		-	-80	-110		$I_{C} = -500$ mA, $I_{B} = -50$ mA	
Collector-Enlitter Saturation voltage (Note To)		-	-180	-310		$I_C = -500 \text{mA}, I_B = -20 \text{mA}$	
		-	-150	-220		$I_{C} = -1A, I_{B} = -100mA$	
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-849	-950	mV	$I_{\rm C} = -1$ A, $I_{\rm B} = -100$ mA	
Base-Emitter Saturation Voltage (Note 10)	V _{BE(on)}	-	-790	-900	mV	$I_{C} = -1A, V_{CE} = -2V$	
Output Capacitance	C _{obo}	-	14.1	20	pF	$V_{CB} = -10V, f = 1MHz$	
Transition Frequency	f _T	-	180	-	MHz	$V_{CE} = -15V, I_C = -20mA, f = 100MHz$	
Delay Time	t _(d)	-	15.8	-	ns		
Rise Time	t _(r)	-	41	-	ns	$V_{CC} = -10V, I_{C} = -500mA,$	
Storage Time	t _(s)	-	411	-	ns	$I_{B1} = I_{B2} = -50 \text{mA}$	
Fall Time	t _(f)	-	89	-	ns		

Notes: 10. Measured under pulsed conditions. Pulse width \leq 300 µs. Duty cycle \leq 2%



Typical Electrical Characteristics @T_A = 25°C unless otherwise specified

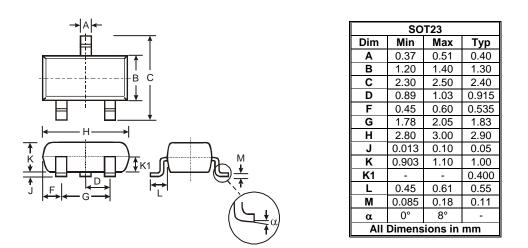






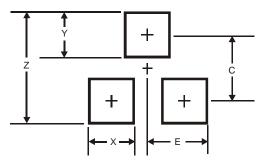
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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